An ISO/TS 16949, ISO 9001 and ISO 14001 Certified Company





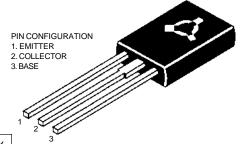
TO-126 (SOT-32) Plastic Package

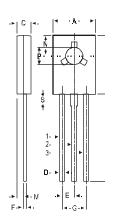
BD165, BD167, BD169

BD165, 167, 169 NPN PLASTIC POWER TRANSISTORS

Complementary BD166, 168, 170

Audio Amplifier and Driver Circuit Applications





DIM	MIN.	MAX.			
A	7.4	7.8			
₿	10.5	10.8			
C	2.4	2.7			
D	0.7	0.9			
Е	2.25 TYP.				
F	0.49	0.75			
G	4.5 TYP.				
L	15.7	TYP.			
M	1.27	TYP.			
N	3.75	TY P .			
P	3.0	3.2			
S	2.5	TYP.			

ALL DIMENSIONS IN MM

ABSOLUTE MAXIMUM RATINGS

			165	167	169	
Collector-base voltage (open emitter)	V_{CBO}	max.	45	60	80	V
Collector-emitter voltage (open base)	V_{CEO}	max.	45	60	80	V
Collector current	I_C	max.		1.5		A
Total power dissipation up to $T_C = 25^{\circ}C$	P_{tot}	max.		20		W
Junction temperature	T_{j}	max.		150		$^{\circ}\!C$
Collector-emitter saturation voltage	,					
$I_C = 0.5 A$; $I_B = 0.05 A$	V_{CEsat}	max.		0.5		V
D.C. current gain						
$I_C = 0.15 A; V_{CE} = 2 V$	h_{FE}	min.		40		

RATINGS (at T_A =25°C unless otherwise specified)

Limiting values			165	167	169	
Collector-base voltage (open emitter)	V_{CBO}	max.	45	60	80	V
Collector-emitter voltage (open base)	V_{CEO}	max.	45	60	80	V
Emitter-base voltage (open collector)	V_{EBO}	max.		5.0		V

Collector current	I_C	max.		1.5		A
Base current	I_{B}	max.		0.5		A
Total power dissipation up to $T_A = 25^{\circ}C$	P_{tot}	max.		1.25		W
Derate above 25°C	101	max		8		mW/ °C
Total power dissipation up to $T_C = 25^{\circ}C$	P_{tot}	max.		20		W
Derate above 25°C	101	max		160		mW °C
Junction temperature	T_i	max.		150		℃
Storage temperature	T_{j} T_{stg}		-65 to +150		150	${\mathcal C}$
THERMAL RESISTANCE						
From junction to case	$R_{th j-c}$			6.25		C/W
From junction to ambient	R _{th j—a}			100		℃/W
CHARACTERISTICS						
$T_{amb} = 25$ °C unless otherwise specified						
0.11			165	167	169	
Collector cutoff current			0.4			
$I_E = 0; V_{CB} = 45 V$	I_{CBO}	max.	0.1		-	mA
$I_E = 0; \ V_{CB} = 60 \ V$	I_{CBO}	max.	_	0.1	-	mA
$I_E = 0; \ V_{CB} = 80 \ V$	I_{CBO}	max.	_	_	0.1	mA
Emitter cut-off current						
$I_C = 0; \ V_{EB} = 5 \ V$	I_{EBO}	max.		1.0		mA
Breakdown voltages						
$I_C = 0.1A; I_B = 0$	$V_{CEO(sus)}^*$	min.	45	60	80	V
$I_C = 1mA; I_E = 0$	V_{CBO}	min.	45	60	80	V
$I_E = 1mA; I_C = 0$	V_{EBO}	min.		5.0		V
DC current gain						
$I_C = 0.15A; V_{CE} = 2V$	h_{FE}^*	m in		40		
$I_C = 0.5A; V_{CE} = 2V$	h_{FE}^*	m in		15		
Saturation voltage						
$I_C = 0.5A$; $I_B = 0.05A$	$V_{CE(sat)}^*$	max.		0.5		V
Base-emitter on voltage						
$I_C = 0.5 A; V_{CE} = 2 V$	$V_{BE(on)}^*$	max.		0.95		V
Transition frequency $f = 1 \text{ MHz}$	_(= -(-,-)					
$I_C = 500 \text{ mA}; V_{CE} = 2 \text{ V}$	f_T	min.		6.0		MHz
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^{*} Pulse test: pulse width $\leq 300~\mu s$; duty cycle $\leq 2\%$.

Notes

Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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